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U.S. UTILITY Patent Application

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PATENT NUMBER and
ISSUE DATE

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10020460	12/18/2001	257	012	2811	Rane

****APPLICANTS:** Ito Jun; Chiyo Toshiaki; Shibata Naoki; Watanabe Hiroshi; Asami Shizuyo; Asami Shinya;

****CONTINUING DATA VERIFIED:**

THIS APPLICATION IS A DIV OF 09/518,724 03/03/2000 U.S. Patent No. 6,426,512

**** FOREIGN APPLICATIONS VERIFIED:**

JAPAN HEI. 11-058128 03/05/1999

JAPAN HEI. 11-060206 03/08/1999

JAPAN HEI. 11-061155 03/09/1999

PG-PUB ☐ DO NOT PUBLISH ☐

RESCIND ☐

Foreign priority claimed ☐ yes ☐ no

35 USC 119 conditions met ☐ yes ☐ no

Verified and Acknowledged Examiners's initials

ATTORNEY DOCKET NO

P 282612 T36-141808M/KOH

TITLE : Group III nitride compound semiconductor device

U.S. DEPT. OF COMM./PAT. & TM.-PTO-436L (Rev. 12-94)

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NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs. Drwg. Print Fig.
		Application Examiner	
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE	
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